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Inclosure Material:

Metal

Overall Length:

Between 1.510 inches and 1.550 inches

Overall Height:

Between 0.250 inches and 0.300 inches

Overall Width:

Between 0.980 inches and 1.050 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact-darlington connected

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-204ae

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Criticality Code Justification:

Feat

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

250.0 collector to emitter voltage/static/base open and 350.0 collector-to-emitter, with voltage between base and emitter and 8.0 emitter to base voltage, dc

Current Rating Per Characteristic:

60.00 amperes source cutoff current and 20.00 amperes source cutoff current

Power Rating Per Characteristic:

250.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Weapons system essential

Test Data Document:

19623-007637 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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